



SANYO Semiconductors

DATA SHEET

LA4630N

Monolithic Linear IC

For Radio Cassette Recorders 9V/12V 3-Dimension Power Amplifier

Features

- Stereo section 9V/3Ω 3W×2, 12V/3Ω 5W×2 : NF-capacitorless power
 - Super bass section 9V/3Ω 6W, 12V/3Ω 10W : output capacitor, B-S capacitorless power
- This chip employs technology for eliminating pins and external connections to realize 3-dimensional power on a single chip. This IC is a single package power amplifier for making sound systems with punch.
- On-chip pop noise suppressor
 - On-chip power switch circuit
 - External and mute functions on chip.
 - Protection functions on chip (thermal protection circuit and BTL section R_L short protection circuit)

Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	$V_{CC \text{ max}}$	no signal*1	20	V
Thermal resistance	θ_{j-c}		2	$^\circ\text{C/W}$
Maximum output current	$I_{O \text{ peak}}$		3	A
Allowable power dissipation	$P_d \text{ max}$	With infinite heat sink	37.5	W
Operating temperature	T_{opr}		-20 to +75	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to +150	$^\circ\text{C}$

Operating Conditions at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V_{CC}		9	V
			12	V
Recommended load resistance	R_L		3 to 8	Ω
Operating voltage	$V_{CC \text{ op}}$	*2	5 to 18	V

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*1 : Operational notes on the maximum supply voltage.

FRONT L/R	BTL	V _{CC} max	Conditions
R _L ≥ 3Ω	R _L ≥ 3Ω	20V	No signal Front L/R input with capacitor R _g = 0 BTL L/R input without capacitor R _g = 0
R _L ≥ 3Ω	R _L ≥ 4Ω	21V	
R _L ≥ 3Ω	R _L ≥ 5Ω	22V	
R _L ≥ 3Ω	R _L ≥ 6Ω	23V	
R _L ≥ 3Ω	R _L ≥ 7Ω	24V	
R _L ≥ 3Ω	R _L ≥ 8Ω	24V	

For power supply transistor regulation, the equivalent power line resistance is 3Ω or greater.

*2 : The upper limit for V_{CC} op is V_{CC} max-2V.

[Design Note]

Select the target P_O under the a rated load/rated supply voltage conditions of R_L = 3 to 8Ω and V_{CC} = 5 to 18V. Make sure that it does not exceed the package Pd max of 37.5W. Note that heavy load and high V_{CC} conditions would bring about power efficiency deterioration depending on the drive design employed.

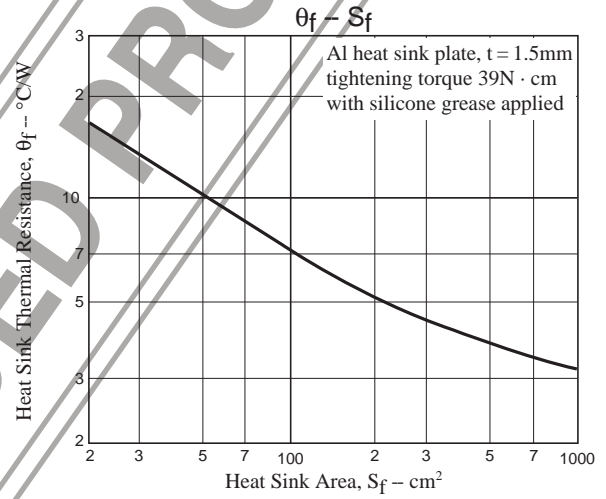
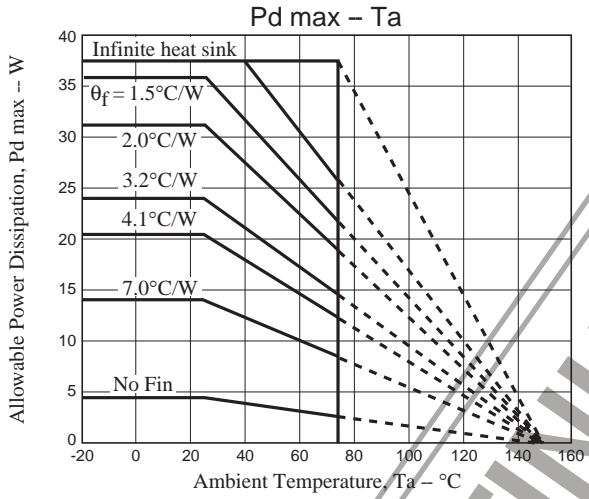
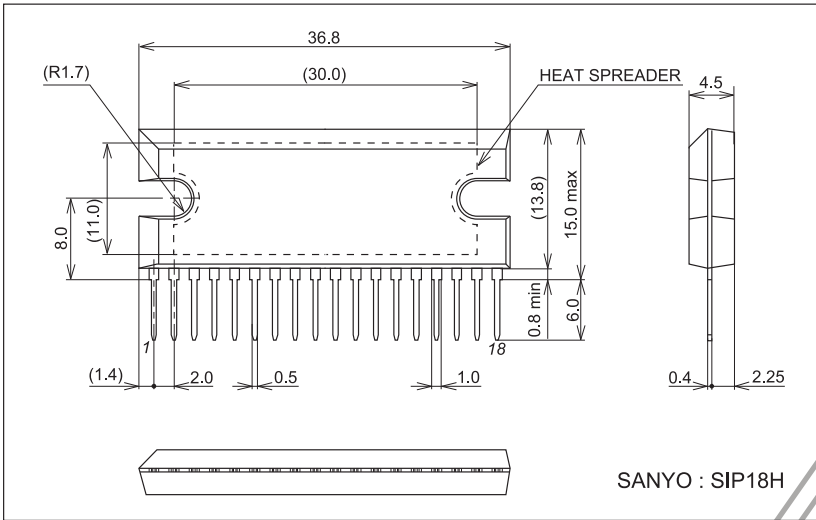
Electrical Characteristics at Ta = 25°C, V_{CC} = 9V, R_L = 3Ω, f = 1kHz

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Quiescent flow-in current	I _{CCO}		35	70	140	mA
Standby current	I _{ST}			1.0	10.0	μA
Power switch pin flow-in current	I _{SW}			10.0		mA
Mute supply flow-in current	I _{CCm}			35.0	70.0	mA
Stereo Section						
Output power	P _{O1}	V _{CC} = 9V, THD = 10%	2.2	3.0		W
	P _{O2}	V _{CC} = 12V, THD = 10%	4.2	5.0		W
Total harmonic distortion	THD	V _O = 1V		0.20	1.0	%
Input resistance	R _i			50		kΩ
Voltage gain	VG		43	45	47	dB
Output noise voltage	V _{NO}	R _g = 0, BPF = 20Hz to 20kHz		0.15	0.40	mV
Ripple rejection	SVRR	f _R = 100Hz, V _R = 0dBm	45	55		dB
Channel separation	CHsep	R _g = 10kΩ, V _O = 0dBm	45	50		dB
Muting attenuation	A _{tt}	V _O = 0dBm		80		dB
Low-region roll off frequency	f _L	VG = -3dB		50		Hz
High-region roll off frequency	f _H	VG = -3dB		50		kHz
Super Bass Section						
Output power	P _{O1}	V _{CC} = 9V, THD = 10%	5.0	6.0		W
	P _{O2}	V _{CC} = 12V, THD = 10%	8.0	10.0		W
Total harmonic distortion	THD	V _O = 1V		0.20	1.0	%
Input resistance	R _i			30		kΩ
Voltage gain	VG		43	45	47	dB
Output noise voltage	V _{NO}	R _g = 0, BPF = 20Hz to 20kHz		0.3	0.6	mV
Ripple rejection	SVRR	f _R = 100Hz, V _R = 0dBm	50	60		dB
Muting attenuation	A _{tt}	V _O = 0dBm		80		dB
Low-region roll off frequency	f _L	VG : -3dB		5		Hz
High-region roll off frequency	f _H	VG : -3dB		40		kHz
Output offset voltage	V _{OFF}	R _g = 0	-150		+150	mV

Package Dimensions

unit : mm (typ)

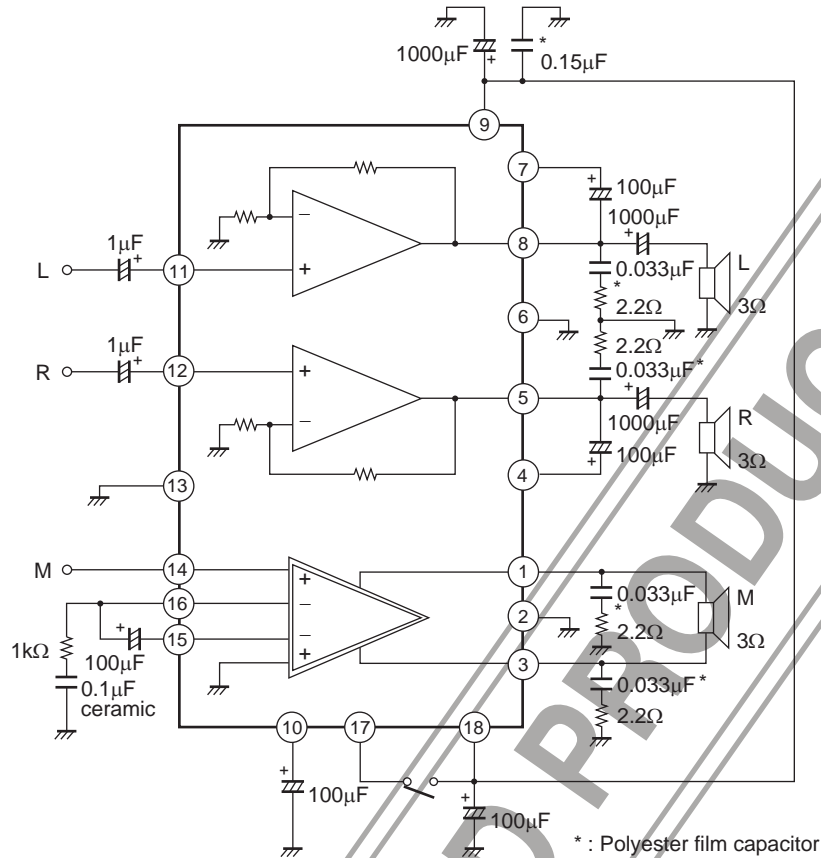
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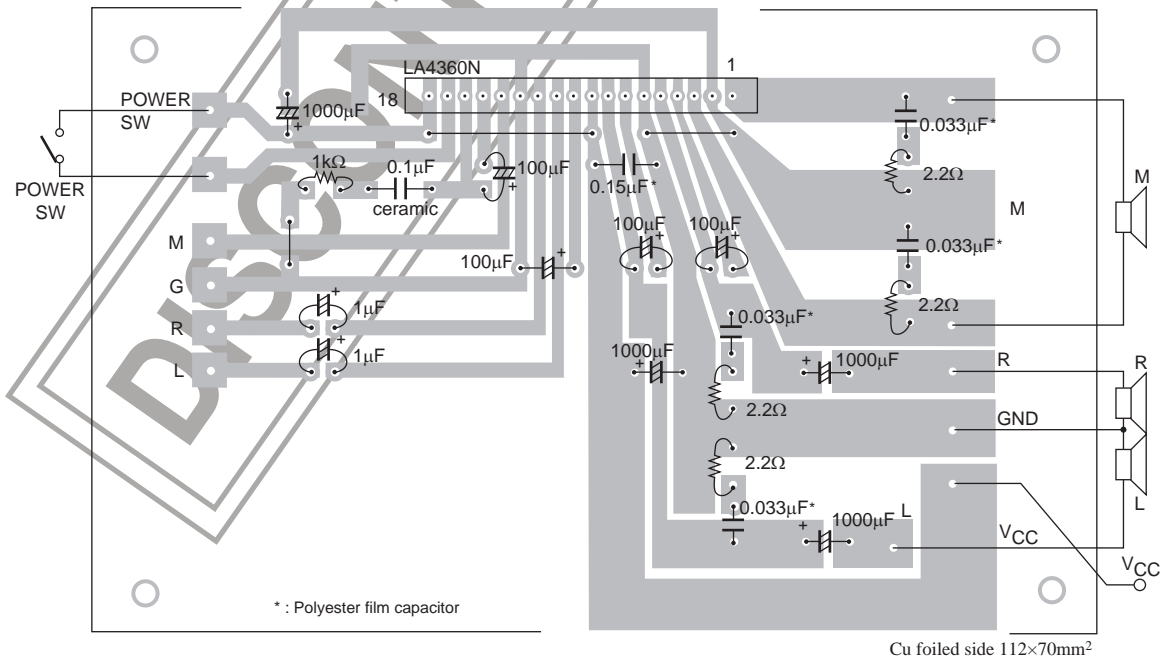
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Block Diagram



- Note 1 : The motor should not be connected to the power switch pin since transient noise may appear on the amplifier outputs when the motor is started or stopped.
- Note 2 : Audio mute is enabled by connecting a 300Ω resistance between the DC pin (pin 10) and ground. DC bias control of both the stereo (L ch, R ch) and BTL (super bass) channels is there enabled, and all audio output signals can be muted by controlling the MUTE pin.

Sample Printed Circuit Pattern



* : Insert 0.15µF between power supply and ground at the root of the pins.

Pin Voltages

Pin No.	1	2	3	4	5	6	7	8	9
Name	OUT No	PWR GND 2	OUT Inv	BS R	OUT R	PWR GND 1	BS L	OUT L	V _{CC} 1
Pin Voltage (V)	4.0	0	4.0	8.1	4.5	0	8.1	4.0	9.0

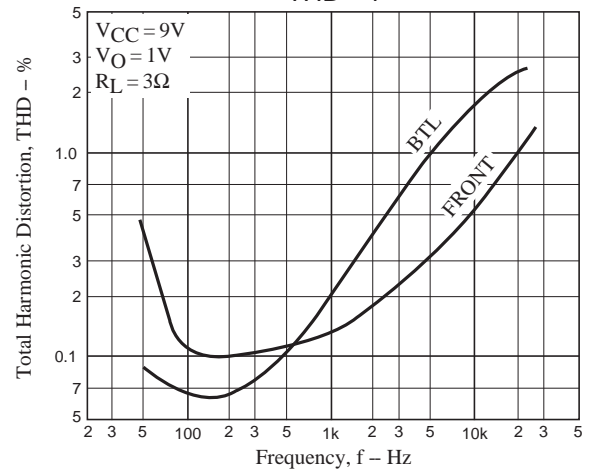
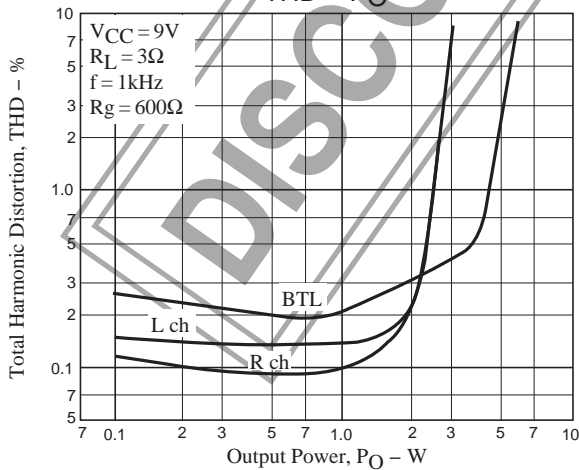
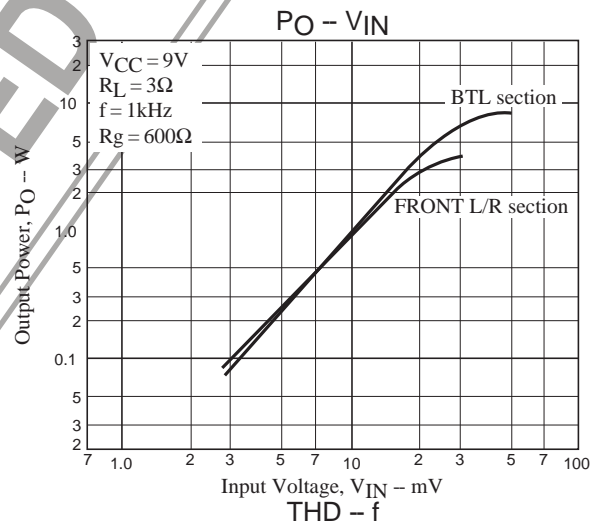
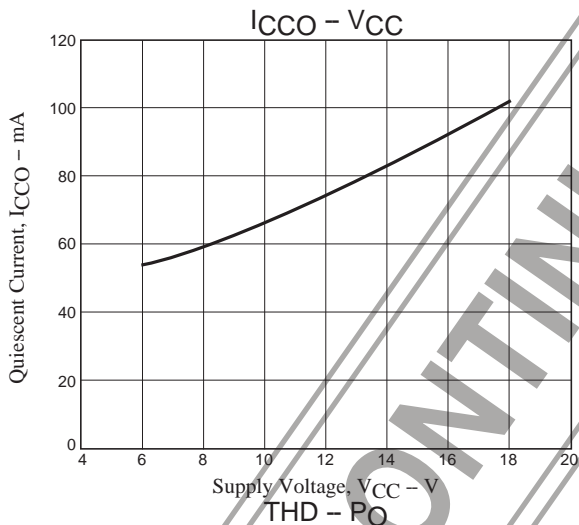
Pin No.	10	11	12	13	14	15	16	17	18
Name	DC	IN L	IN R	PRE GND	IN No	NF Inv	NF No	PWR SW	V _{CC} 2
Pin Voltage (V)	4.5	1.4	1.4	0	21 [mV]	1.4	1.4	9.0	9.0

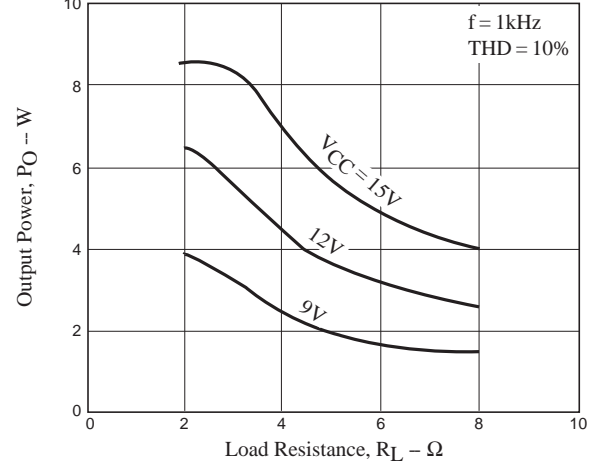
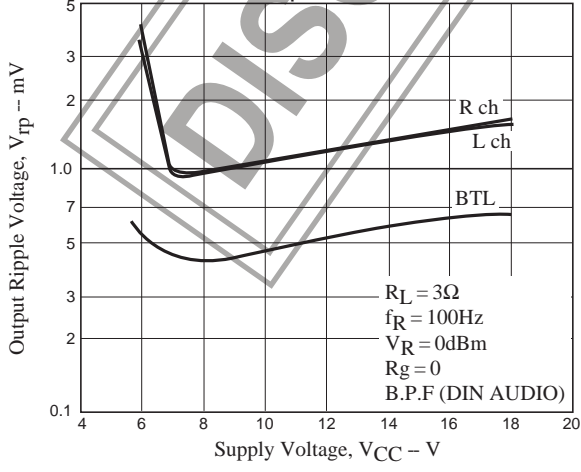
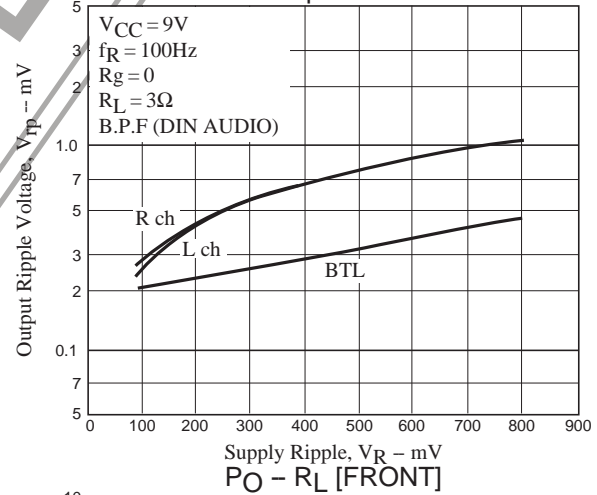
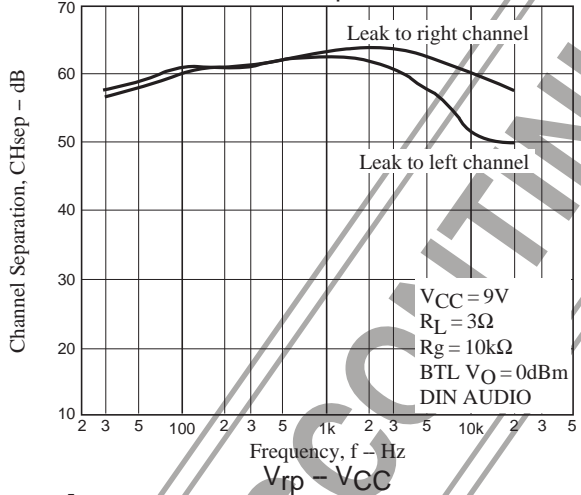
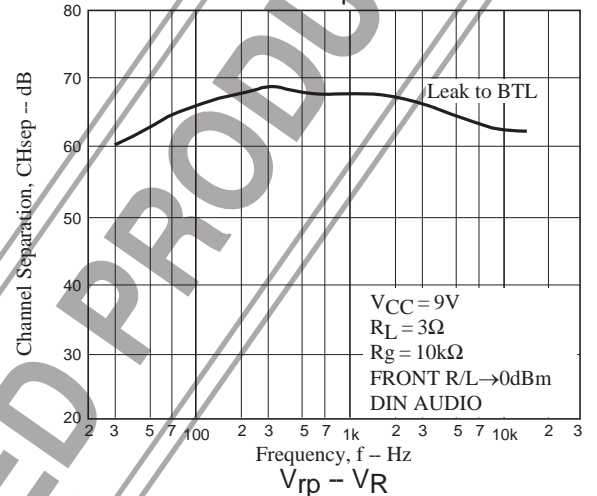
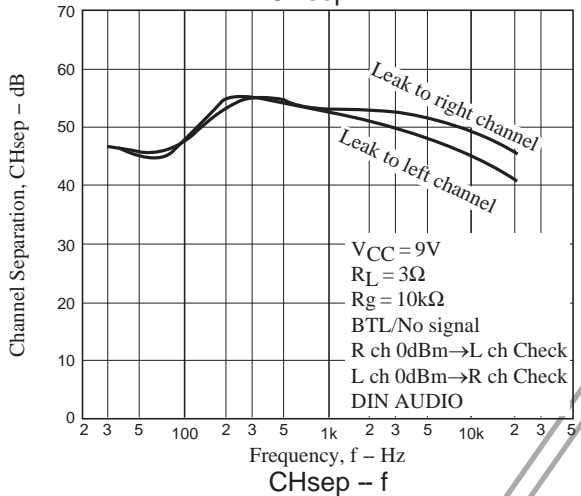
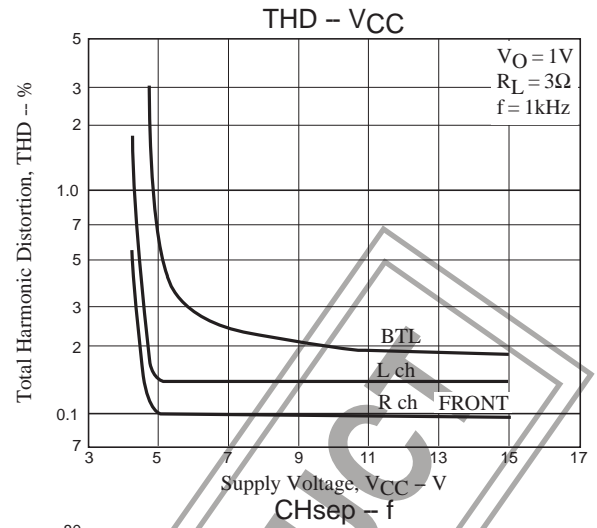
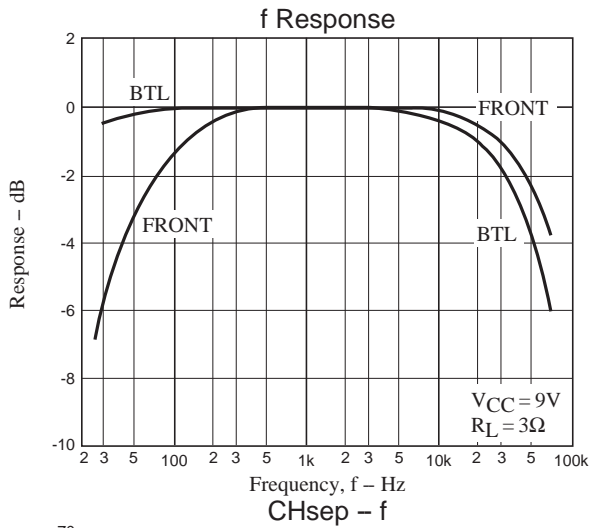
P_O Chart (THD = 10%)

Item	R _L	9V	12V	15V
FRONT L/R	8Ω	1.4W	2.5W	3.9W
	6Ω	1.75W	3.2W	5.0W
	4Ω	2.4W	4.3W	6.4W
	3Ω	3.2W	5.6W	-
BTL	8Ω	3.2W	6.4W	11.0W
	6Ω	4.0W	8.1W	13.5W
	4Ω	5.3W	10.4W	-
	3Ω	6.4W	12.4W	-

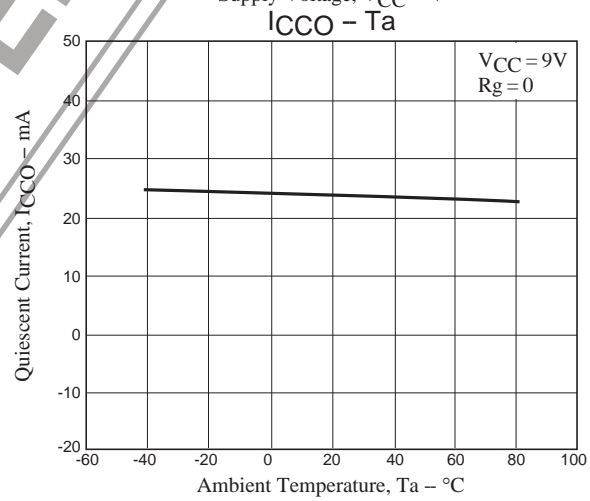
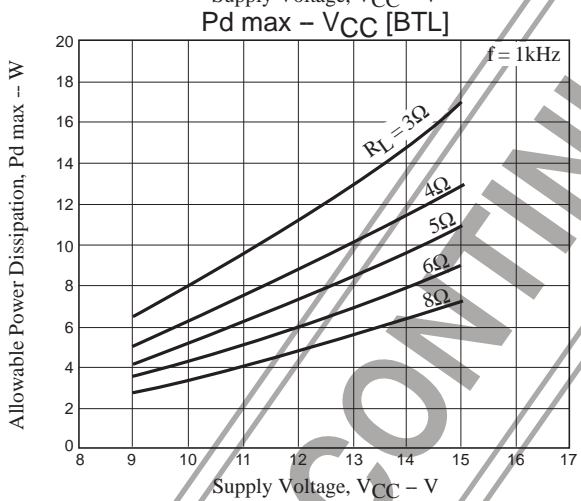
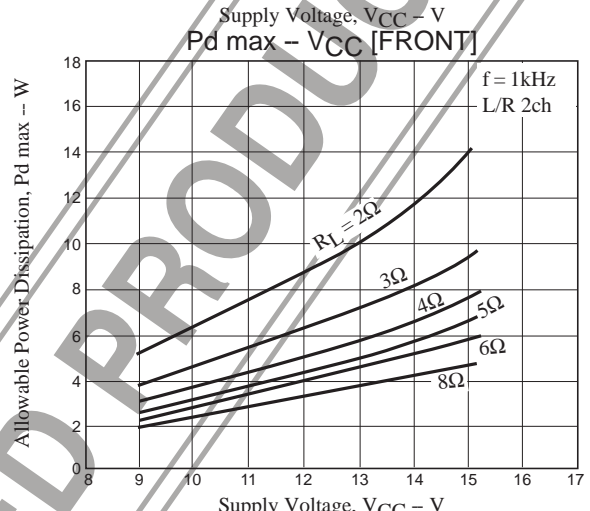
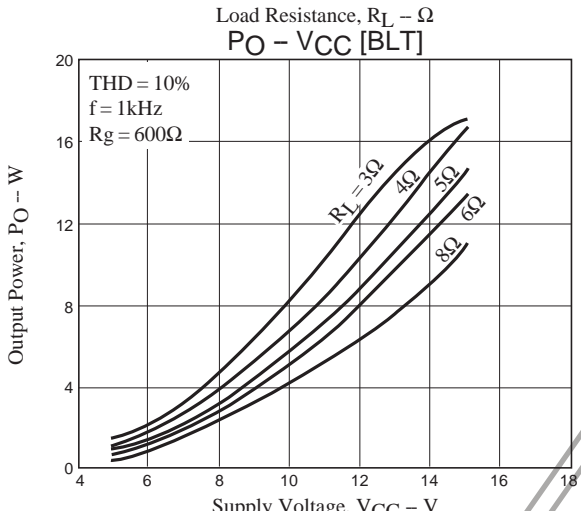
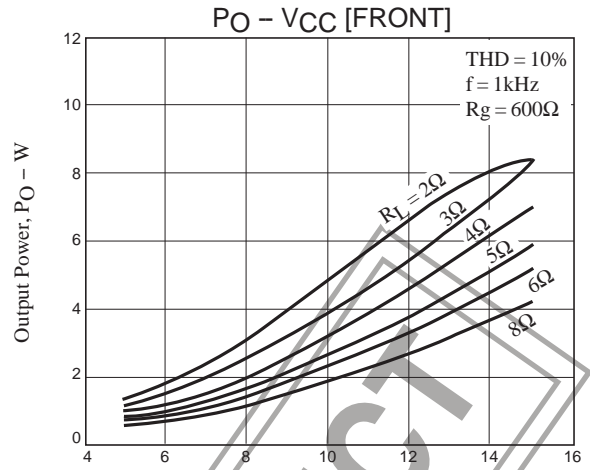
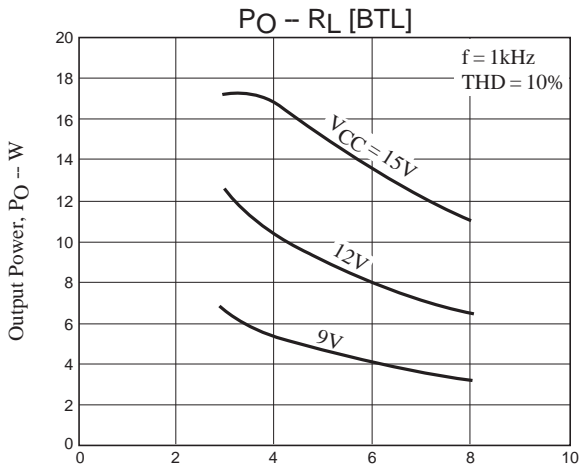
P_d max Chart

Item	R _L	9V	12V	15V
FRONT L/R	8Ω	2.0W	3.2W	4.6W
	6Ω	2.4W	3.8W	5.7W
	4Ω	3.1W	5.0W	5.4W
	3Ω	3.8W	6.2W	-
BTL	8Ω	2.8W	4.8W	7.2W
	6Ω	3.6W	6.0W	9.0W
	4Ω	5.0W	8.8W	-
	3Ω	6.3W	11.2W	-





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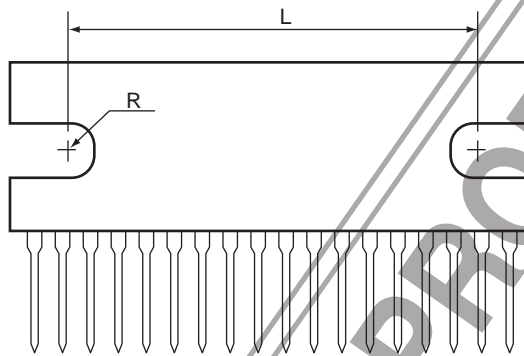
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Notes on using this IC

- Always short power supply pins 9 and 16 on the copper foil of the printed circuit pattern and apply the equivalent power supply voltage.
- Pin 17 is designed for the power switch.
It can be switched on and off with a small current capacity switch, but the point to watch out for is that if the voltage loss between pins 17 and 18 is too large, there may be problems in the biasing and the power may drop.
- When switching with a transistor, the general practice is to insert a PNP transistor between pins 17 and 18.

Notes on Mounting Radiator Fin

1. The tightening torque should be in the range of 39 to 59N · cm.
2. The distance between screw holes of the radiator fin must coincide with the distance between screw holes of the IC. With case outline dimensions L and R referred to, the screws must be tightened with the distance between them as close to each other as possible.



3. The screw to be used must have a head equivalent to the one of truss machine screw or binder machine screw defined by JIS. Washers must be also used to protect the IC case.
4. No foreign matter such as cutting particles must exist between heat sink and radiator fin. When applying grease on the junction surface, it must be applied uniformly on the whole surface.
5. IC lead pins must be soldered to the printed circuit board after the radiator fin is mounted on the IC.

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